## Student ID #:\_\_\_\_\_

## **EECS 170A**

Homework #5 HW will be collected in discussion section. Please do not turn your HW in **anywhere else.** Due: 10:50am Thursday, November 3, 2011.

Please staple this sheet to the front of your homework.

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1) The following is the Ideal Diode equation:

 $I = I_o (e^{qV_{diode}/kT} - 1)$ 

Take  $I_{o} = 10^{-15}$  A. For the circuit shown in the figure below, fill in the following table:



$V_{AC}(V)$	$V_{\text{Diode}}(V)$	$V_{BC}(V)$
-10V		
-7.5V		
-5V		
0V		
5V		
7.5V		
10V		

2) Assume a Solar Cell that is 100% efficient. In board daylight, the sun energy is  $1 \text{kW} / \text{m}^2$ . The area of the Solar Cell is  $1 \text{ m}^2$ . All energy is converted to electron-hole pairs. With  $V_{\text{Applied}} = 0$ , What amount of current is flowing through the Solar Cell? (I<sub>solar</sub>).

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3) Using the following schematic for reference:



Now using: 
$$I_{total} = I_{solar} + I_o (e^{qV_{bi}/kT} - 1)$$

Find the available power from the Solar Cell that is delivered to the Load Resistor.

4)For a PN junction with  $N_A = 10^{18} \text{ cm}^{-3}$  and  $N_D = 10^{14} \text{ cm}^{-3}$ . a)Draw the Band Diagram under 0 Bias, 0.1V Forward Bias, -1V Reverse Bias, and -10V Reverse Bias. b) Find built in Voltage (V<sub>bi</sub>) in Volts.